

# LEAD-FREE / RoHS-COMPLIANT

## **HIGH POWER BIAS TEE**

The BTN2-0026 is constructed using a custom-made, resonance-free conical inductor to achieve extremely broadband performance. By minimizing the overall inductor size and using proprietary packaging techniques, the BTN2-0026 is a superior option in terms of performance, reliability and ease-of-use when compared to cumbersome user-designed bias tees employing off-the-shelf conical inductors. The extremely low cutoff and resonance free operation makes the BTN2-0026 suitable for biasing amplifiers, lasers, and modulators driven with high frequency data patterns.



**BTN2-0026** 

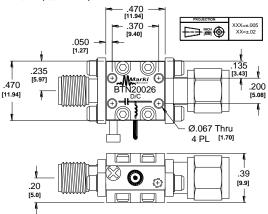
#### Features

- Broadband: 3 MHz to 26.5 GHz
- Low Insertion Loss
- High Power
- Non-Resonant
- Compact Size

Electrical Specifications - Specifications guaranteed from -55 to +100°C, measured in a 50Ω system.
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Parameter	Frequency Range	Min	Тур	Мах
Insertion Loss (dB)	10 MHz-26.5 GHz		1	2
	3-10 MHz		2	
	3 MHz -1 GHz		50	
DC Port Isolation (dB)	1-26.5 GHz		30	
Return Loss (dB)			14	
RF Power (W)	3 MHz-26.5 GHz			10
DC Current (A)				2
DC Voltage (V)				50
DC Resistance (Ω)			0.3	
Inductance (uH)			4.7	
Capacitance (nF)			100	
Weight (g)			10	
Risetime /Falltime (ps) <sup>1</sup>			10	

<sup>1</sup>Specified as 90%/10%. Calculated from  $\tau_{bt}^2 = (\tau_{out}^2 - \tau_{in}^2)$ 



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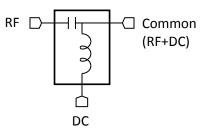


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#### **Schematic**



#### **Application Examples**

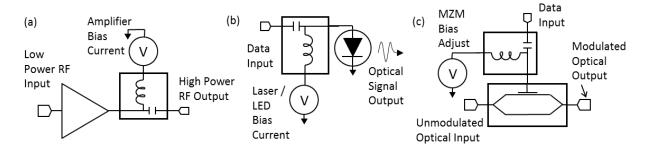
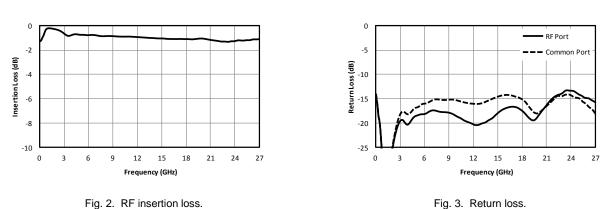


Fig. 1. Example Schematics of a) Broadband Microwave Amplifier Biasing, b) Laser/LED Biasing for Data Communication and c) Mach-Zender Modulator Biasing for Data Communication



# **Typical Performance**

Fig. 3. Return loss.



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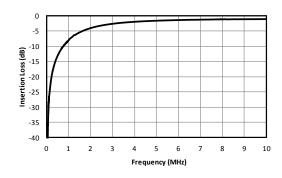
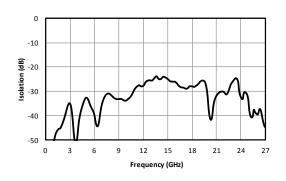


Fig. 4. Low frequency RF response.





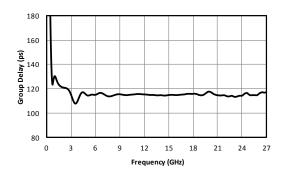


Fig. 8. Group delay.

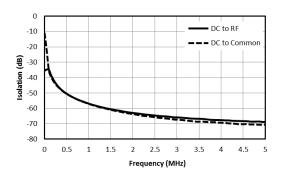
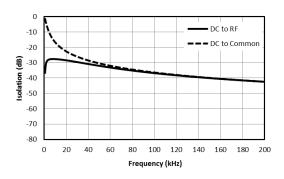


Fig. 5. Low frequency isolation.





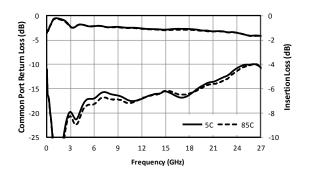


Fig. 9. Performance over temperature

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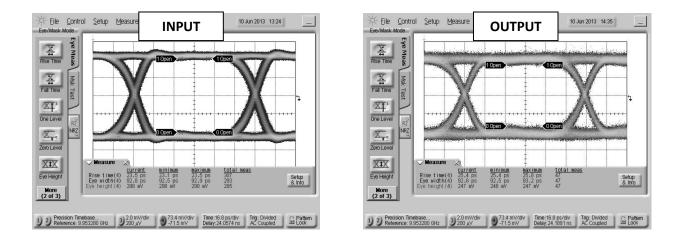


Fig. 10. Oscilloscope measurements of the BTN2-0026 with a 10Gb/s PRBS pattern. Eye diagrams are taken with a 2<sup>31</sup>-1 PRBS input demonstrating minimal eye distortion/closure afforded by the extremely low frequency operation of the bias tee.

Model Number	Description	
BTN2-0026	3 MHz to 26.5 GHz High Power Bias Tee	
	with SMA connectors <sup>1</sup> , LEAD-FREE/RoHS COMPLIANT	

<sup>1</sup>Consult factory for other connector options.

#### **Revision History**

Revision code	Revision Date	Comment
В	May 2020	RoHS Compliant Assembly

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